



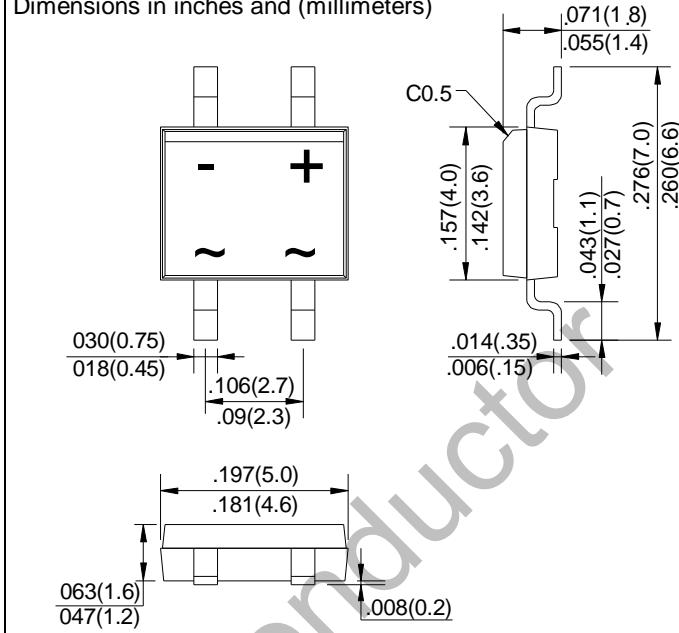
MB6F - MB10F Bridge Rectifiers

Features

- Requires Only 35 mm² of Board Space
- High Surge Current Capability: 30A (max)
- Glass Passivated Junction Rectifiers

MBF

Dimensions in inches and (millimeters)



Absolute Maximum Ratings * T_A = 25°C unless otherwise noted

Symbol	Parameter	Value			Units
		MB6F	MB8F	MB10F	
V _{RRM}	Maximum Repetitive Peak Reverse Voltage	600	800	1000	V
V _{RMS}	Maximum RMS Voltage	420	560	700	V
V _{DC}	Maximum DC Blocking Voltage	600	800	1000	V
I _{F(AV)}	Average Rectified Forward Current	0.8			A
I _{FSM}	Peak Forward Surge Current **	30			A
I ² t	I ² t Rating for fusing (t<8.3ms)	3.735			A ² S
T _J	Operating Junction Temperature Range	-55 to +150			°C
T _{STG}	Storage Temperature Range	-55 to +150			°C

* 60Hz sine wave, R-load, T_A = 25°C on FR-4 PCB.

** 60Hz sine wave, Non-repetitive 1 cycle peak value, T_J = 25°C.

Thermal Characteristics*

Symbol	Parameter	Typ.	Units
R _{θJA}	Thermal Resistance, Junction-Ambient - Measurement with Dual Dice - Measurement with Single Die	250 150	°C/W °C/W
Ψ _{JL}	Thermal Characterization, Junction to Lead - Measured at Anode pin - Measured at Cathode pin	57 15	°C/W °C/W

* Device mounted on FR-4 PCB with board size = 76.2mm x 114.3mm (JESD51-3 standards)

Electrical Characteristics T_A = 25°C unless otherwise specified

Symbol	Parameter	Test condition	Value	Units
V _F	Maximum Forward Voltage	I _F = 1A, Pulse measurement, Per diode	1.1	V
I _R	Maximum Reverse Current	@ V _{RRM} , Pulse measurement, Per diode	10	µA
C _J	Typical Junction Capacitance	V _R = 4V, f = 1MHz	10	pF

Typical Characteristics

Fig.1 - Maximum Forward Current Derating Curve

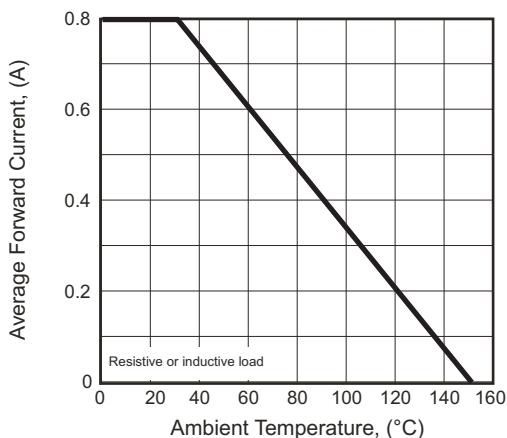


Fig.2 - Maximum Non-repetitive Forward Surge Current Per Bridge Element

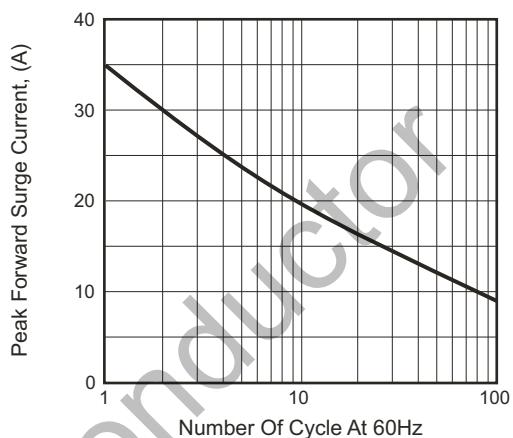


Fig.3 - Typical Instantaneous Forward Characteristics Per Bridge Element

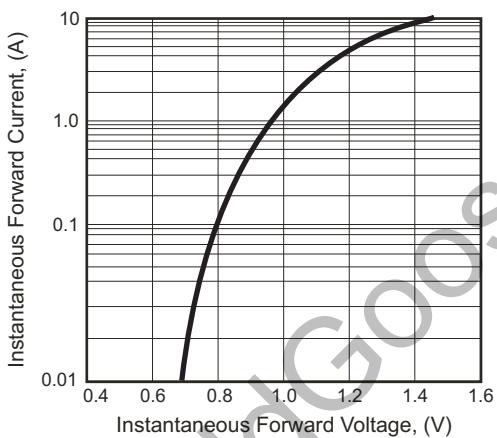


Fig.4 - Typical Reverse Characteristics Per Bridge Element

